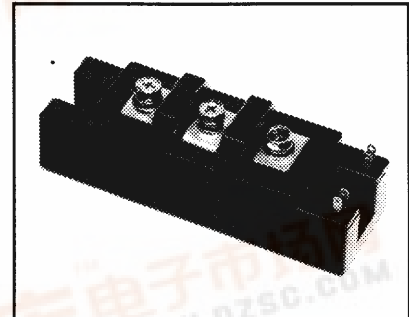
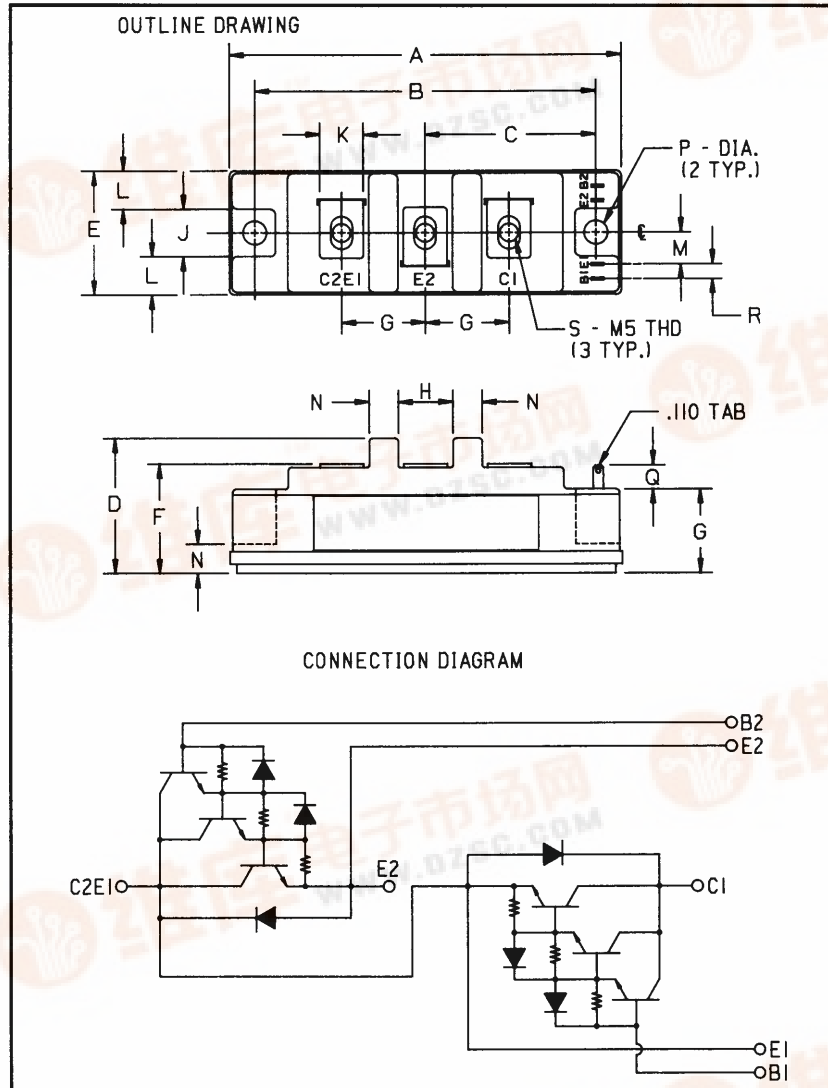




Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KD221K75

Dual Darlington Transistor Module 75 Amperes/1000 Volts



Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

Features:

- Isolated Mounting
- Planar Chips
- Discrete Fast Recovery Feedback Diode
- High Gain (h_{FE})
- Quick Connect Base-Emitter Signal Terminals
- Base-Emitter Speed-up Diodes

Applications:

- AC Motor Control
- DC Motor Control
- Switching Power Supplies
- Inverters

Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KD221K75 is a 1000 Volt, 75 Ampere Dual Darlington Module.

Type	$V_{CE0(sus)}$ Volts (1000)	Current Rating Amperes (75)
KD22	1K	75

Outline Drawing

Dimensions	Inches	Millimeters
A	4.252 Max.	108 Max.
B	3.661 ± 0.012	93 ± 0.3
C	1.831	46.5
D	1.457	37
E	1.339 Max.	34 Max.
F	1.181 Max.	30 Max.
G	0.906	23
H	0.591	15
J	0.512	13

Dimensions	Inches	Millimeters
K	0.472	12
L	0.413	10.5
M	0.344	8.75
N	0.315	8
P	0.256 Dia.	6.5 Dia.
Q	0.256 Min.	6.5 Min.
R	0.157	4
S	M5 Metric	M5





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Absolute Maximum Ratings, $T_J = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	KD221K75	Units
Junction Temperature	T_J	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(sus)}$	1000	Volts
Collector-Base Voltage	V_{CBO}	1000	Volts
Emitter-Base Voltage	V_{EBO}	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	V_{CEV}	1000	Volts
Continuous Collector Current	I_C	75	Amperes
Diode Forward Current	I_{FM}	75	Amperes
Continuous Base Current	I_B	4	Amperes
Diode Surge Current	I_{FSM}	700	Amperes
Power Dissipation (Each Transistor)	P_t	500	Watts
Max. Mounting Torque M5 Terminal Screws	-	17	in.-lb.
Max. Mounting Torque M6 Mounting Screws	-	26	in.-lb.
Module Weight (Typical)	-	250	Grams
V Isolation	V_{RMS}	2500	Volts

Electrical Characteristics, $T_J = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector Cutoff Current	I_{CEV}	$V_{CE} = 1000\text{V}, V_{BE} = -2\text{V}$	-	-	1	mA
		$V_{CE} = 1000\text{V}, V_{BE} = -2\text{V}, T_C = 125^\circ\text{C}$	-	-	10	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 7\text{V}$	-	-	200	mA
DC Current Gain	h_{FE}	$I_C = 75\text{A}, V_{CE} = 5\text{V}$	100	-	-	-
Diode Forward Voltage	V_{FM}	$I_{FM} = 75\text{A}$	-	-	1.8	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 75\text{A}, I_B = 1.5\text{A}$	-	-	2.5	Volts
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 75\text{A}, I_B = 1.5\text{A}$	-	-	3.5	Volts
Resistive Turn-on	t_{on}	$V_{CC} = 600\text{V}$	-	-	2.5	μs
Load Storage Time	t_s	$I_C = 75\text{A}$	-	-	15	μs
Switch Times Fall Time	t_f	$I_{B1} = 1.5\text{A}, I_{B2} = -1.5\text{A}$	-	-	3.0	μs

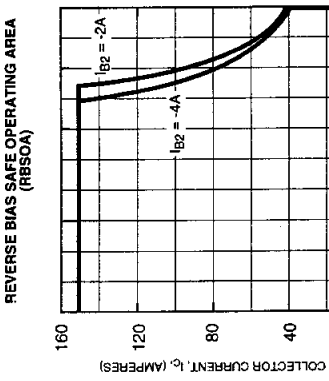
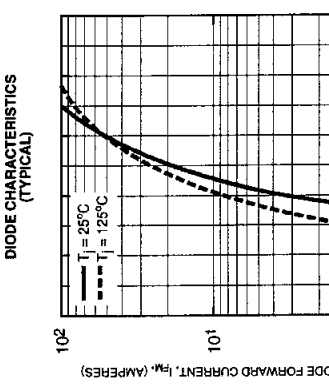
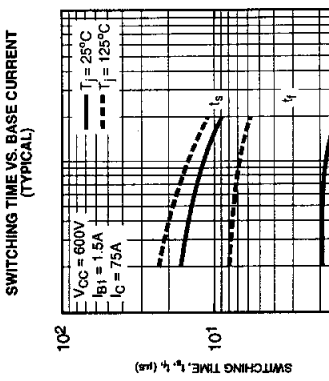
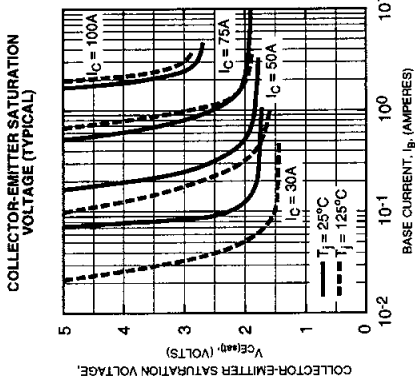
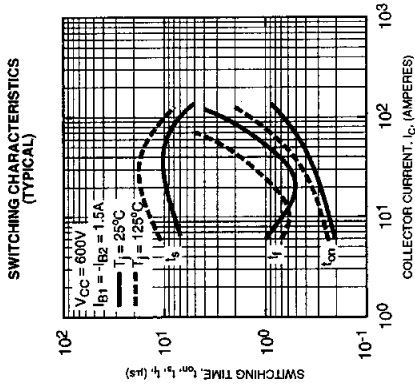
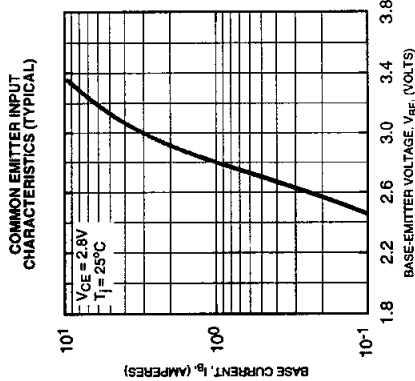
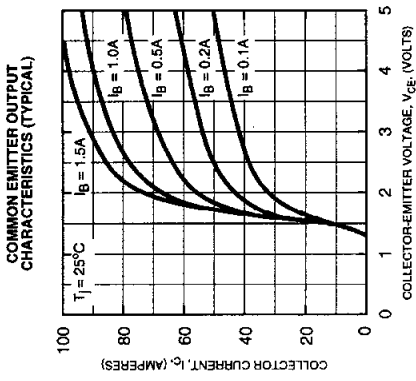
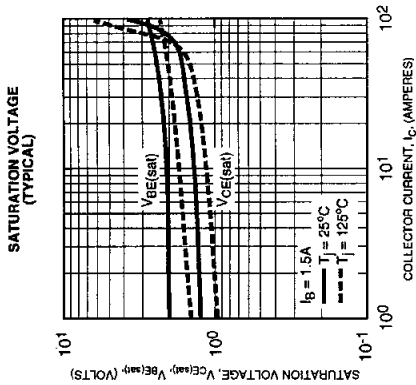
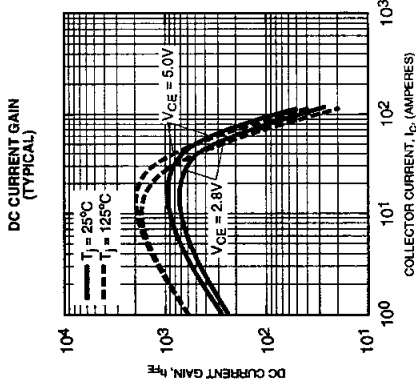
Thermal and Mechanical Characteristics, $T_J = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
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